

# Mems Multimorph Capacitive Temperature Sensors in Comsol Multiphysics $^{\textcircled{\mathbb{R}}}$

Level 3 Semiconductor, Physics and Devices

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November 17, 2017

#### Abstract

This report describes how the C-T characteristics of MEMS multimorph capacitive temperature sensors vary with geometry, material choice and thermal-annealing temperature. The sensors were modelled using FEM and physics simulation software—Comsol Multiphysics —so the key design choices for the model and mesh are also included.

## Nomenclature

MEMS Microelectromechanical systems

## 1 Introduction

why sense temperature?
what temperature sensors are available?
why MEMS?

# 2 Background

what is a multimorph capacitor?

#### 2.1 Construction

how do we build an effective multimorph how do we make the sensor practical

## 2.2 Characterisation

multimorph capacitance how do we characterise sensitivity? how do we characterise linearity?

## 3 Modelling

## 3.1 Geometry

symmetry dimensions

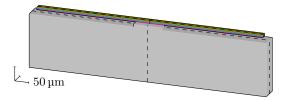


Figure 1: Symmetry lines of the multimorph capacitive temperature sensor—marked with dashed lines.

mesh

- 3.2 Materials
- 3.3 Physics
- 4 Results
- 5 Analysis
- 6 Conclusion



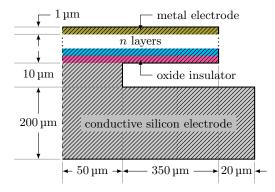


Figure 2: Cross-section of the multimorph temperature sensor—not to scale.